

DATA SHEET

SCHOTTKY BARRIER RECTIFIERS

VOLTAGE

150 Volts

CURRENT

20.0Amperes

ITO-220AB

Unit:mm

MIN

15.67

12.90

Α

С

F

G

Н

J

MILLIMETERS

MAX

16.07

13.30

FEATURES

- Metal of silicon rectifier, majority carrier conducton
- Guard-Ring for Stress Protection.
- Low power loss, high efficiency
- High current capability, low VF
- High surge capacity
- ullet Plastic package has UL flammability classification 94V-0 ${f G}$

9.96 10.36 6.50 6.90 2.65 2.75 1.20 1.24 1.26 1.46 0.70 0.90 2.34 2.74 2.32 2.72 0.60 0.90

MECHANICAL DATA

• Case : ITO-220AB molded plastic • Polarity : As marked on the body

• Mounting position : Any



K L 0.45 0.60 4.53 M 4.93 1.30 1.70 0 3.35 3.45 Р 2.56 Q 3.15 3.25 2.20 2.45

In compliance with EU RoHs 2002/95/EC directives

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°Cambient temperature unless otherwise specified.

Single phase, half wave, 60HZ, resistive or inductive load.

For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL			MBR20150FCT	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM			150	V
Maximum RMS Voltage	VRMS			105	V
Maximum DC Blocking Voltage	Vcc			150	V
Average Rectifier Forward Current (per diode)	IF (AV)			10	A
Total Device (Rated VR) @TC=125°C				20	
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	IFSM			150	A
Maximum Instantaneous Forward Voltage	IF=10A	Tc=25℃ Tc=125℃	VF	0. 92 0. 85	V
Instantaneous Reverse Current	AT VRM	Tc=25℃ Tc=125℃	IR	0. 05 15	MA
Typical Thermal Resistance	ROJC			3. 6	°C/W
Operating Temperature Range	TJ			-55to+175	$^{\circ}$ C
Storage Temperature Range	TSTG			-55to+175	°C





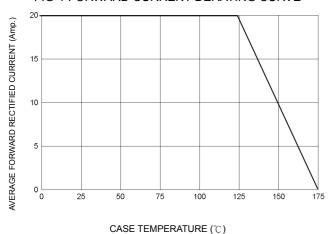
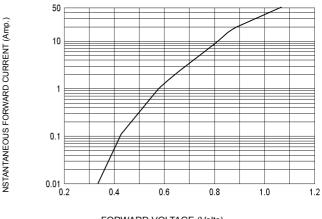


FIG-2 TYPICAL FORWARD CHARACTERISITICS



FORWARD VOLTAGE (Volts)

FIG-3 TYPICAL REVERSE CHARACTERISTICS

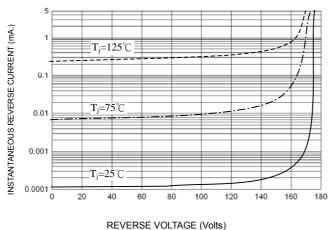
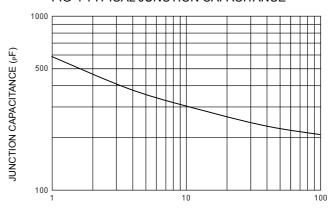
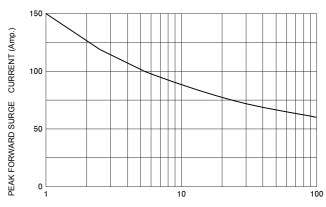


FIG-4 TYPICAL JUNCTION CAPACITANCE



REVERSE VOLTAGE (Volts)

FIG-5 PEAK FORWARD SURGE CURRENT



NUMBER OF CYCLES AT 60 Hz